

**Product data sheet** 

### 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Trench MOSFET technology
- Leadless ultra small and ultra thin SMD plastic package: 1.1 × 1.0 × 0.37 mm
- Exposed drain pad for excellent thermal conduction
- ElectroStatic Discharge (ESD) protection 1.5 kV HBM
- Drain-source on-state resistance  $R_{DSon}$  = 59 m $\Omega$
- Very low gate-source threshold voltage for portable applications  $V_{GS(th)}$  = -0.68 V

### 3. Applications

- High-side load switch and charging switch for portable devices
- Power management in battery driven portables
- LED driver
- DC-to-DC converter

### 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-	-12	V
V <sub>GS</sub>	gate-source voltage	-		-8	-	8	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-	-3.2	А
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -3.2 A; T <sub>j</sub> = 25 °C		-	59	72	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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### 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain	4 3	G ( The second s
4	D	drain	Transparent top view DFN1010D-3 (SOT1215)	S 017aaa259

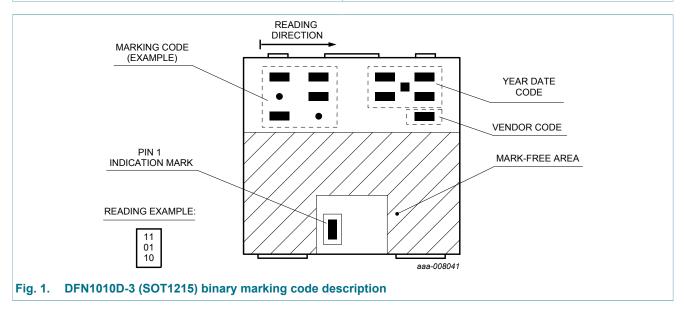
# 6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMXB65UPE	DFN1010D-3	DFN1010D-3: plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 1.1 x 1.0 x 0.37 mm	SOT1215				

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PMXB65UPE	01 10 00



PMXB65UPE

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### 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit		
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-12	V		
V <sub>GS</sub>	gate-source voltage			-8	8	V		
I <sub>D</sub>	drain current	$V_{GS}$ = -4.5 V; $T_{amb}$ = 25 °C	[1]	-	-3.2	А		
		$V_{GS}$ = -4.5 V; $T_{amb}$ = 100 °C	[1]	-	-2.1	А		
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-13	А		
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	317	mW		
			[1]	-	1070	mW		
		T <sub>sp</sub> = 25 °C		-	8330	mW		
Tj	junction temperature			-55	150	°C		
T <sub>amb</sub>	ambient temperature			-55	150	°C		
T <sub>stg</sub>	storage temperature			-65	150	°C		
Source-dra	Source-drain diode							
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-1	А		

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

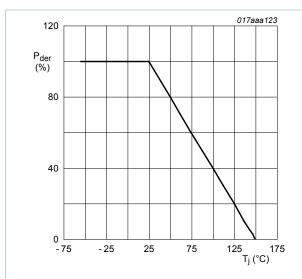


Fig. 2. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

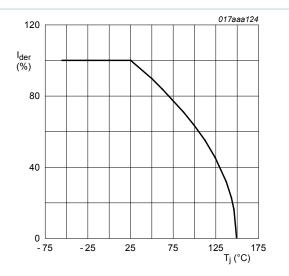
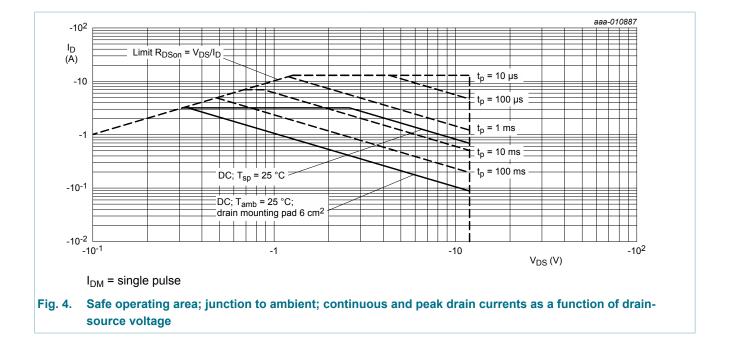


Fig. 3. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^\circ \text{C})}} \times 100 \%$$

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#### 12 V, P-channel Trench MOSFET



### 9. Thermal characteristics

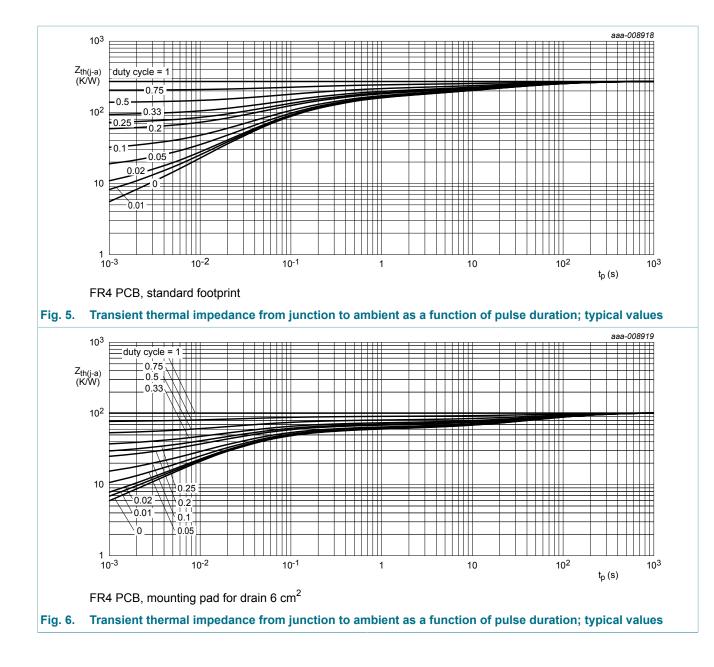
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]	-	271	312	K/W
			[2]	-	102	117	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point			-	10	15	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.



#### 12 V, P-channel Trench MOSFET



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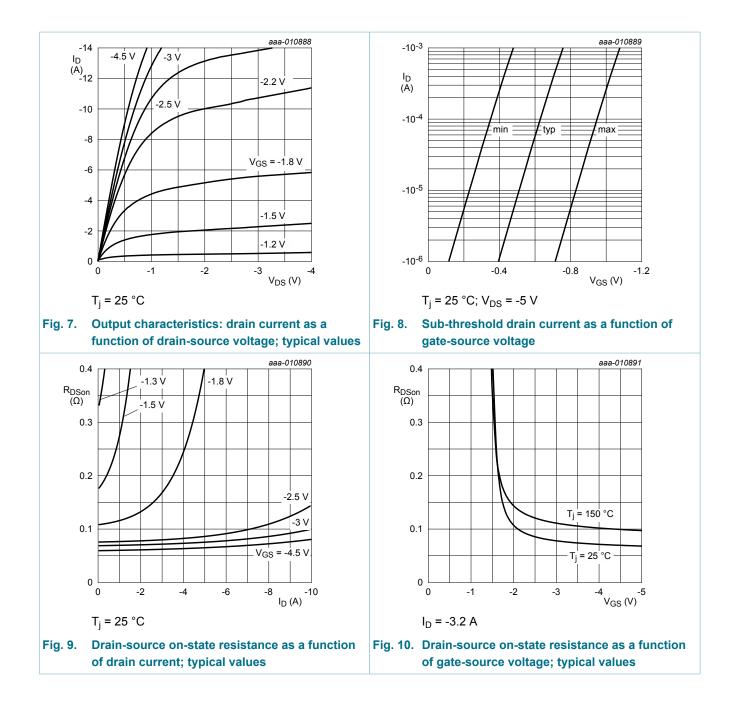
12 V, P-channel Trench MOSFET

# **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	cteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = -250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-12	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = -250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	-0.4	-0.68	-1	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = -12 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
I <sub>GSS</sub>	gate leakage current	$V_{GS}$ = -8 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-10	μA
		$V_{GS}$ = 8 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	10	μA
		$V_{GS}$ = -4.5 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
		V <sub>GS</sub> = 4.5 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	1	μA
R <sub>DSon</sub>	drain-source on-state	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -3.2 A; T <sub>j</sub> = 25 °C	-	59	72	mΩ
	resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -3.2 A; T <sub>j</sub> = 150 °C	-	80	98	mΩ
		$V_{GS}$ = -2.5 V; I <sub>D</sub> = -2.7 A; T <sub>j</sub> = 25 °C	-	78	98	mΩ
		$V_{GS}$ = -1.8 V; I <sub>D</sub> = -0.4 A; T <sub>j</sub> = 25 °C	-	120	200	mΩ
		$V_{GS}$ = -1.5 V; I <sub>D</sub> = -50 mA; T <sub>j</sub> = 25 °C	-	198	450	mΩ
		$V_{GS}$ = -1.2 V; I <sub>D</sub> = -10 mA; T <sub>j</sub> = 25 °C	-	880	-	mΩ
9fs	forward transconductance	V <sub>DS</sub> = -10 V; I <sub>D</sub> = -2 A; T <sub>j</sub> = 25 °C	-	9.4	-	S
R <sub>G</sub>	gate resistance	f = 1 MHz	-	8.7	-	Ω
Dynamic ch	aracteristics	· · · · ·	I			
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -6 V; I <sub>D</sub> = -3.2 A; V <sub>GS</sub> = -4.5 V;	-	6.7	12	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	1	-	nC
Q <sub>GD</sub>	gate-drain charge		-	1.9	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = -6 V; f = 1 MHz; $V_{GS}$ = 0 V;	-	634	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	167	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	146	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -6 V; I <sub>D</sub> = -3.2 A; V <sub>GS</sub> = -4.5 V;	-	6.2	-	ns
r	rise time	R <sub>G(ext)</sub> = 6 Ω; T <sub>j</sub> = 25 °C	-	22	-	ns
td(off)	turn-off delay time		-	27	-	ns
t <sub>f</sub>	fall time		-	17	-	ns
Source-drai	n diode		I		1	
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -1 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.7	-1.2	V

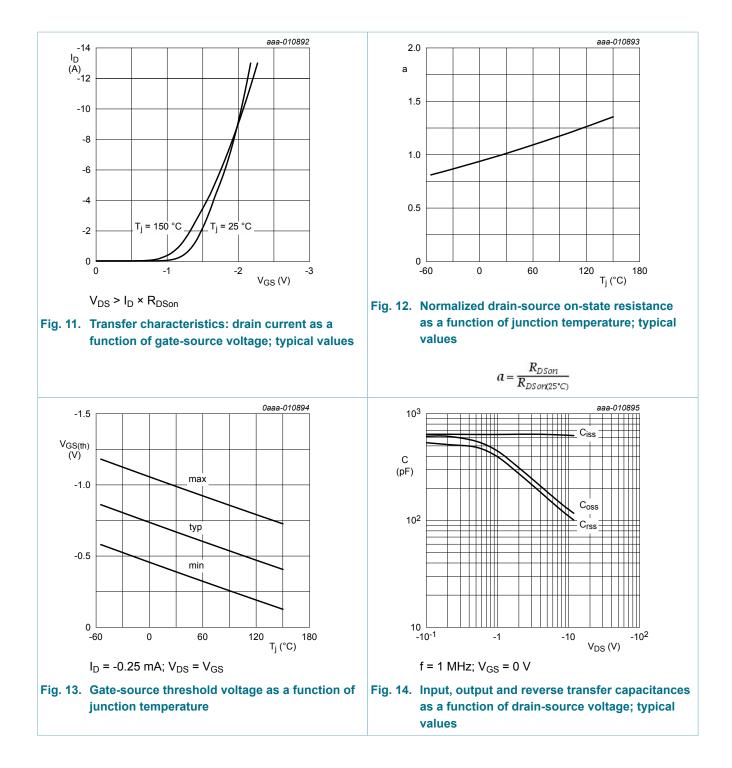
# **PMXB65UPE**

#### 12 V, P-channel Trench MOSFET



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#### 12 V, P-channel Trench MOSFET

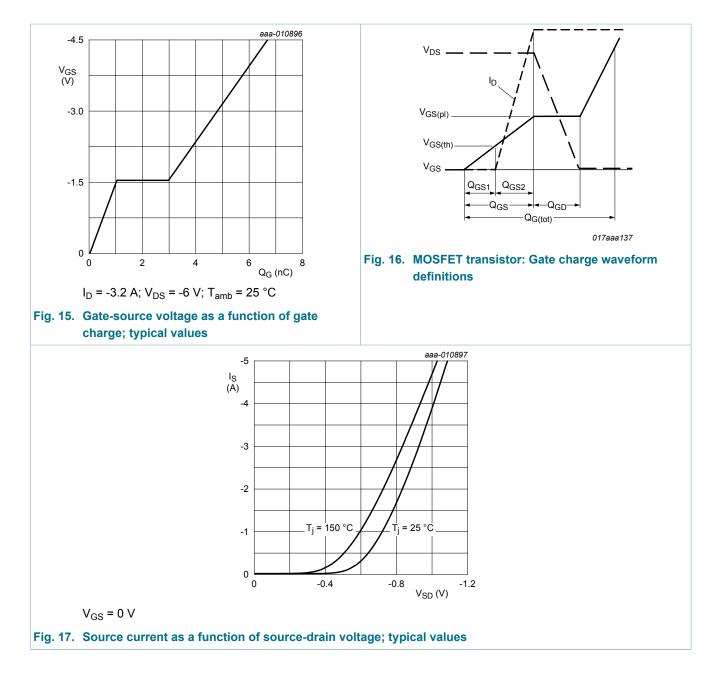


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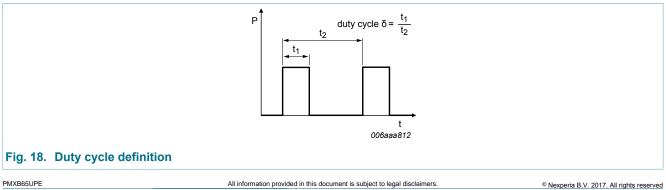
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# **PMXB65UPE**

#### 12 V, P-channel Trench MOSFET

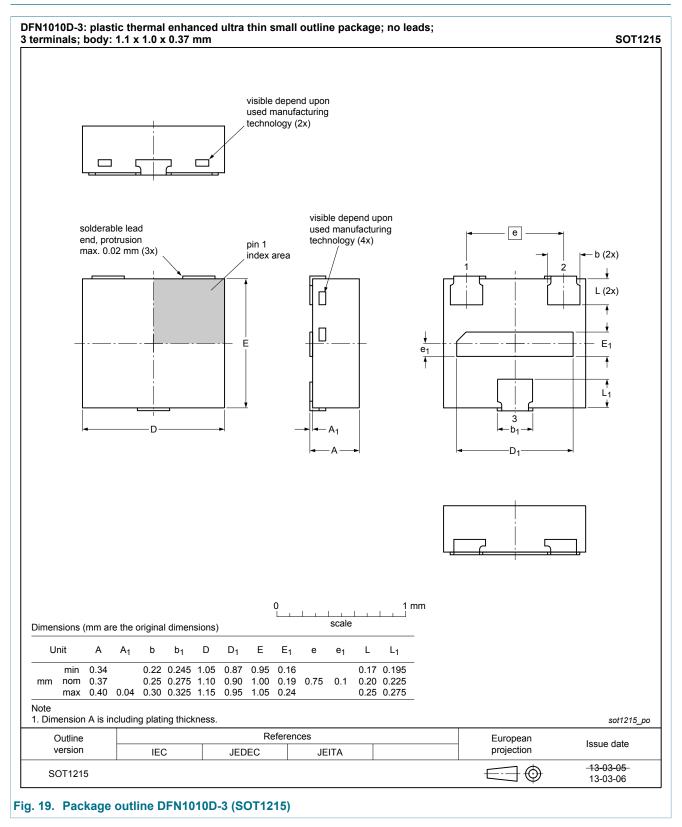


# **11. Test information**



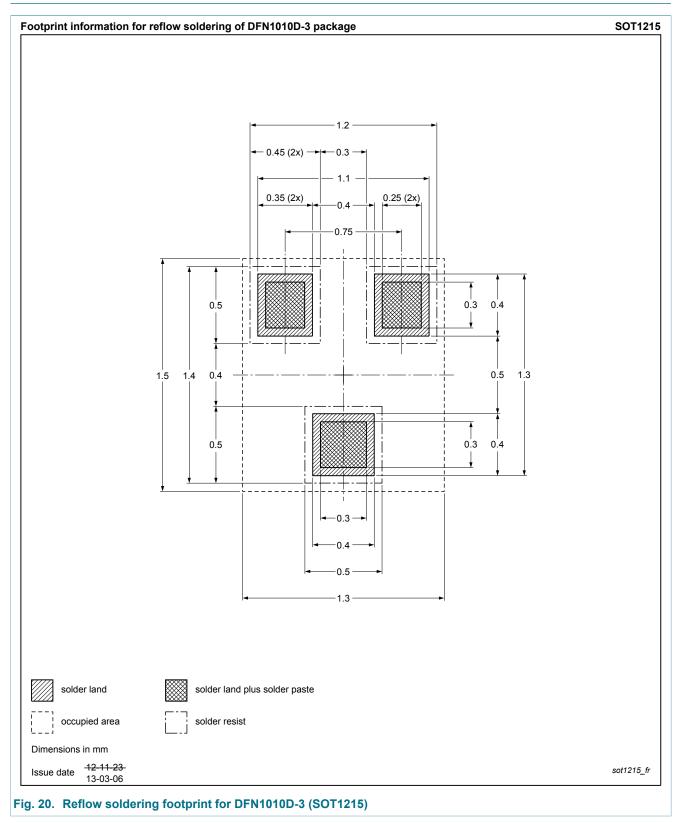
#### 12 V, P-channel Trench MOSFET

### **12. Package outline**



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### **13. Soldering**



# 14. Revision history

Table 8. Revision his	story			
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMXB65UPE v.3	20140708	Product data sheet	-	PMXB65UPE v.2
Modifications:	Product status char	iged		
PMXB65UPE v.2	20140218	Preliminary data sheet	-	PMXB65UPE v.1
PMXB65UPE v.1	20140204	Preliminary data sheet	-	-

#### 12 V, P-channel Trench MOSFET

### 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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